# BACHELOR OF TECHNOLOGY (C.B.C.S.) (2021-COURSE) B. Tech. Sem - II E&TC :SUMMER- 2022 SUBJECT : SEMICONDUCTOR DEVICES & CIRCUITS-I

Day: Wednesday
Date: 3/8/2022

S-24102-2022

Time: 10:00 AM-01:00 PM

Max. Marks: 60

# N.B.:

- 1) All questions are **COMPUSLORY**.
- 2) Figures to the right indicate FULL marks.
- 3) Draw neat and labeled diagram WHEREVER necessary.
- 4) Assume suitable data if necessary.
- 5) Use of non-programmable **CALCULATOR** is allowed.
- Q.1 State the limitations of half-wave rectifier. Show that the efficiency of a half-wave rectifier is 40.6%.

## OR

- Q.1 Draw the circuit diagram for a voltage quadrupler and state its working. What (10) are the applications of a voltage multiplier circuit?
- Q.2 Design a fixed current bias circuit using a BJT with  $\beta = 100$ , Vcc = + 15V to (10) set the Q-point at (5V, 3mA).

#### OR

- Q.2 For a fixed current bias circuit,  $Rb = 180k\Omega$ ,  $Rc = 2k\Omega$ , and Vcc = 12V. (10) Assuming Vbe = 0.7V, find the dc operating point (Q point) when  $\beta = 50$ .
- Q.3 A common emitter circuit uses a transistor with hfe = 50, hie = 1.2 k $\Omega$ , and hoe =  $10^{-6}$  S. Rc = 3.9 k $\Omega$ , Re = 4.7 k $\Omega$ , R1 = 68 k $\Omega$ , R2 = 56 k $\Omega$ , RL = 82 k $\Omega$ . Calculate the input impedance, output impedance, voltage gain, current gain and power gain.

#### OR

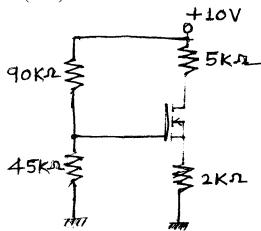
- Q.3 For a common base voltage amplifier, derive the expressions for input (10) impedance, output impedance, voltage gain and current gain. Draw the ac equivalent circuit for the same.
- Q.4 Design a gate bias circuit for JFET to have Id(max) = 3mA and VDS(min) = (10)10V, given VDD = 25V, VGS(off) = -6V, IDSS = 8mA,  $RG = 1 M\Omega$ .

### OR

Q.4 Draw a FET common source amplifier circuit with bypassed Rs and its AC (10) equivalent circuit and derive the equation for its voltage gain.

P.T.O.

Q.5 Determine IDQ and VDSQ for the following circuit. Given: VT = 1V,  $K'(W/L) = 2mA/V^2$  (10)



OR

- Q.5 State and explain the various MOSFET models used for design and analysis (10) of MOSFET circuits.
- Q.6 Explain the concept of current mirror with a basic BJT current mirror circuit. (10)

OR

Q.6 Explain the Widlar current source with a neat circuit diagram. (10)

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